



T-67-21-55

MM54HC138/MM74HC138

3-to-8 Line Decoder

General Description

This decoder utilizes advanced silicon-gate CMOS technology, and is well suited to memory address decoding or data routing applications. The circuit features high noise immunity and low power consumption usually associated with CMOS circuitry, yet has speeds comparable to low power Schottky TTL logic.

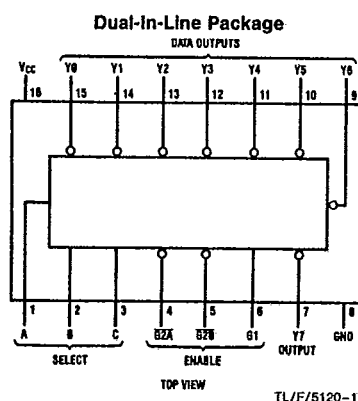
The MM54HC138/MM74HC138 has 3 binary select inputs (A, B, and C). If the device is enabled these inputs determine which one of the eight normally high outputs will go low. Two active low and one active high enables ($\overline{G1}$, $\overline{G2A}$ and $\overline{G2B}$) are provided to ease the cascading of decoders.

The decoder's outputs can drive 10 low power Schottky TTL equivalent loads, and are functionally and pin equivalent to the 54LS138/74LS138. All inputs are protected from damage due to static discharge by diodes to V_{CC} and ground.

Features

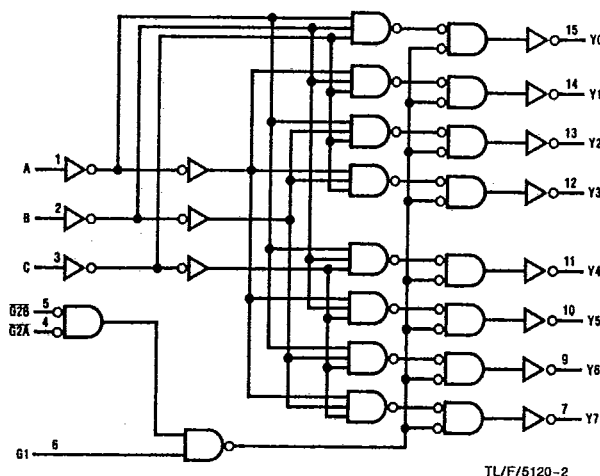
- Typical propagation delay: 20 ns
- Wide power supply range: 2V-6V
- Low quiescent current: 80 μ A maximum (74HC Series)
- Low input current: 1 μ A maximum
- Fanout of 10 LS-TTL loads

Connection and Logic Diagrams



Order Number MM54HC138*
or MM74HC138*

*Please look into Section 8, Appendix D for availability of various package types.



Truth Table

Inputs		Outputs							
Enable	Select								
$\overline{G1}$ $\overline{G2}^*$	C B A	Y0	Y1	Y2	Y3	Y4	Y5	Y6	Y7
X H	X X X	H	H	H	H	H	H	H	H
L X	X X X	H	H	H	H	H	H	H	H
H L	L L L	L	H	H	H	H	H	H	H
H L	L L H	H	L	H	H	H	H	H	H
H L	L H L	H	H	L	H	H	H	H	H
H L	L H H	H	H	H	L	H	H	H	H
H L	H L L	H	H	H	H	L	H	H	H
H L	H L H	H	H	H	H	H	L	H	H
H L	H H L	H	H	H	H	H	H	L	H
H L	H H H	H	H	H	H	H	H	H	L

* $\overline{G2} = \overline{G2A} + \overline{G2B}$

H = high level, L = low level, X = don't care

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Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CC})	-0.5 to +7.0V
DC Input Voltage (V_{IN})	-1.5 to $V_{CC} + 1.5V$
DC Output Voltage (V_{OUT})	-0.5 to $V_{CC} + 0.5V$
Clamp Diode Current (I_{IK}, I_{OK})	± 20 mA
DC Output Current, per pin (I_{OUT})	± 25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	± 50 mA
Storage Temperature Range (T_{STG})	-65°C to +150°C
Power Dissipation (P_D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temp. (T_L) (Soldering 10 seconds)	260°C

Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	2	6	V
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temp. Range (T_A)			
MM74HC	-40	+85	°C
MM54HC	-55	+125	°C
Input Rise or Fall Times (t_r, t_f)			
$V_{CC} = 2.0V$		1000	ns
$V_{CC} = 4.5V$		500	ns
$V_{CC} = 6.0V$		400	ns

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V _{CC}	T _A = 25°C		74HC T _A = -40 to 85°C		54HC T _A = -55 to 125°C		Units
				Typ	Guaranteed Limits					
V _{IH}	Minimum High Level Input Voltage		2.0V		1.5	1.5	1.5	V		
			4.5V		3.15	3.15	3.15	V		
			6.0V		4.2	4.2	4.2	V		
V _{IL}	Maximum Low Level Input Voltage**		2.0V		0.5	0.5	0.5	V		
			4.5V		1.35	1.35	1.35	V		
			6.0V		1.8	1.8	1.8	V		
V _{OH}	Minimum High Level Output Voltage	V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 20 μA	2.0V	2.0	1.9	1.9	V			
			4.5V	4.5	4.4	4.4	V			
			6.0V	6.0	5.9	5.9	V			
		V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 4.0 mA I _{OUT} ≤ 5.2 mA	4.5V	4.2	3.98	3.84	V			
			6.0V	5.7	5.48	5.34	V			
V _{OL}	Maximum Low Level Output Voltage	V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 20 μA	2.0V	0	0.1	0.1	V			
			4.5V	0	0.1	0.1	V			
			6.0V	0	0.1	0.1	V			
		V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 4.0 mA I _{OUT} ≤ 5.2 mA	4.5V	0.2	0.26	0.33	V			
			6.0V	0.2	0.26	0.33	V			
I _{IN}	Maximum Input Current	V _{IN} = V _{CC} or GND	6.0V		±0.1	±1.0	±1.0	μA		
I _{CC}	Maximum Quiescent Supply Current	V _{IN} = V _{CC} or GND I _{OUT} = 0 μA	6.0V		8.0	80	160	μA		

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: -12 mW/°C from 65°C to 85°C; ceramic "J" package: -12 mW/°C from 100°C to 125°C.

Note 4: For a power supply of 5V $\pm 10\%$ the worst case output voltages (V_{OH} and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at $V_{CC} = 5.5V$ and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN} , I_{CC} , and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

** V_{IL} limits are currently tested at 20% of V_{CC} . The above V_{IL} specification (30% of V_{CC}) will be implemented no later than Q1, CY89.

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AC Electrical Characteristics $V_{CC}=5V$, $T_A=25^\circ C$, $C_L=15\text{ pF}$, $t_r=t_f=6\text{ ns}$ **T-67-21-55**

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
t_{PLH}	Maximum Propagation Delay, Binary Select to any Output		18	25	ns
t_{PHL}	Maximum Propagation Delay, Binary Select to any Output		28	35	ns
t_{PHL} , t_{PLH}	Maximum Propagation Delay, G1 to any Output		18	25	ns
t_{PHL}	Maximum Propagation Delay $\overline{G2A}$ or $\overline{G2B}$ to Output		23	30	ns
t_{PLH}	Maximum Propagation Delay $\overline{G2A}$ or $\overline{G2B}$ to Output		18	25	ns

AC Electrical Characteristics $C_L=50\text{ pF}$, $t_r=t_f=6\text{ ns}$ (unless otherwise specified)

Symbol	Parameter	Conditions	V _{CC}	T _A = 25°C		74HC	54HC	Units
						T _A = -40 to 85°C	T _A = -55 to 125°C	
				Typ	Guaranteed Limits			
t _{PLH}	Maximum Propagation Delay Binary Select to any Output Low to High		2.0V	75	150	189	224	ns
			4.5V	15	30	38	45	ns
			6.0V	13	26	32	38	ns
t _{PHL}	Maximum Propagation Delay Binary Select to any Output High to Low		2.0V	100	200	252	298	ns
			4.5V	20	40	50	60	ns
			6.0V	17	34	43	51	ns
t _{PHL} , t _{PLH}	Maximum Propagation Delay G1 to any Output		2.0V	75	150	189	224	ns
			4.5V	15	30	38	45	ns
			6.0V	13	26	32	38	ns
t _{PHL}	Maximum Propagation Delay $\overline{G2A}$ or $\overline{G2B}$ to Output		2.0V	82	175	221	261	ns
			4.5V	28	35	44	52	ns
			6.0V	22	30	37	44	ns
t _{PLH}	Maximum Propagation Delay $\overline{G2A}$ or $\overline{G2B}$ to Output		2.0V	75	150	189	224	ns
			4.5V	15	30	38	45	ns
			6.0V	13	26	32	38	ns
t _{TLH} , t _{THL}	Output Rise and Fall Time		2.0V	30	75	95	110	ns
			4.5V	8	15	19	22	ns
			6.0V	7	13	16	19	ns
C _{IN}	Maximum Input Capacitance			3	10	10	10	pF
C _{PD}	Power Dissipation Capacitance	(Note 5)		75				pF

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.